

isc N-Channel MOSFET Transistor

TK8Q65W, ITK8Q65W

• FEATURES

- Low drain-source on-resistance:
 R_{DS}(on) ≤0.67Ω.
- Enhancement mode: Vth =2.5 to 3.5V (Vps = 10 V, Ip=0.3mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

· Switching Voltage Regulators

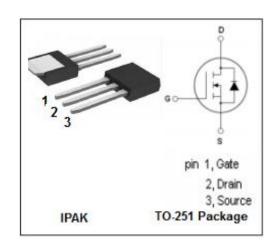


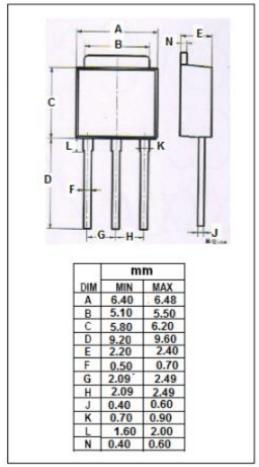
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous	7.8	А
I _{DM}	Drain Current-Single Pulsed	31.2	А
P _D	Total Dissipation @T _C =25℃	80	W
Tj	Max. Operating Junction Temperature	150	${\mathbb C}$
T _{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.57	°C/W
Rth(ch-a)	th(ch-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =10mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10V; I _D =0.3mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =3.9A			670	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μА
l _{DSS}	Drain-Source Leakage Current	V _{DS} =650V; V _{GS} = 0V			10	μА
V _{SDF}	Diode forward voltage	I _{DR} =7.8A, V _{GS} = 0 V			1.7	V

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